NSN 5962-01-120-4847

Memory Microcircuit - Page 1 of 1

Fiig: A458a0



View Online at https://aerobasegroup.com/nsn/5962-01-120-4847 **Body Length:** 0.840 inches **Body Width:** Between 0.220 inches and 0.310 inches **Body Height:** Between 0.140 inches and 0.185 inches **Maximum Power Dissipation Rating:** 739.0 milliwatts **Operating Tempurature Range:** -55.0/+125.0 degrees celsius Storage Tempurature Range: -65.0/+150.0 degrees celsius **Features Provided:** Programmed and w/enable and high impedance and schottky and bipolar **Inclosure Material:** Ceramic **Inclosure Configuration:** Dual-in-line **Case Outline Source And Designator:** D-2 mil-m-38510 **Terminal Surface Treatment:** Solder Voltage Rating And Type Per Characteristic: -0.5 volts power source and 7.0 volts power source **Time Rating Per Chacteristic:** 75.00 nanoseconds propagation delay time, high to low level output and 75.00 nanoseconds propagation delay time, low to high level output **Memory Device Type:** Prom **Terminal Type And Quantity:** 16 printed circuit Shelf Life: N/a **Unit Of Measure:** Demilitarization: Yes - demil/mli